

PN4250A
SILICON
PNP TRANSISTOR



TO-92 CASE

DESCRIPTION:

The CENTRAL SEMICONDUCTOR PN4250A is a silicon PNP transistor designed for low level, low noise amplifier applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

| | |
|--|--|
| Collector-Base Voltage | |
| Collector-Emitter Voltage | |
| Collector-Emitter Voltage | |
| Emitter-Base Voltage | |
| Continuous Collector Current | |
| Power Dissipation | |
| Operating and Storage Junction Temperature | |
| Thermal Resistance | |
| Thermal Resistance | |

| SYMBOL | | UNITS |
|----------------|-------------|--------------------|
| V_{CBO} | 60 | V |
| V_{CES} | 60 | V |
| V_{CEO} | 60 | V |
| V_{EBO} | 5.0 | V |
| I_C | 500 | mA |
| P_D | 625 | mW |
| T_J, T_{stg} | -65 to +150 | $^\circ\text{C}$ |
| θ_{JC} | 83.3 | $^\circ\text{C/W}$ |
| θ_{JA} | 200 | $^\circ\text{C/W}$ |

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

| SYMBOL | TEST CONDITIONS | MIN | MAX | UNITS |
|---------------|---|-----|------|------------------|
| I_{CBO} | $V_{CB}=50\text{V}$ | | 10 | nA |
| I_{EBO} | $V_{EB}=3.0\text{V}$ | | 20 | nA |
| BV_{CBO} | $I_C=10\mu\text{A}$ | 60 | | V |
| BV_{CES} | $I_C=10\mu\text{A}$ | 60 | | V |
| BV_{CEO} | $I_C=5.0\text{mA}$ | 60 | | V |
| BV_{EBO} | $I_E=10\mu\text{A}$ | 5.0 | | V |
| $V_{CE(SAT)}$ | $I_C=10\text{mA}, I_B=0.5\text{mA}$ | | 0.25 | V |
| h_{FE} | $V_{CE}=5.0\text{V}, I_C=100\mu\text{A}$ | 250 | 700 | |
| C_{ob} | $V_{CB}=5.0\text{V}, f=1.0\text{MHz}$ | | 6.0 | pF |
| h_{fe} | $V_{CE}=5.0\text{V}, I_C=1.0\text{mA}, f=1.0\text{kHz}$ | 250 | 800 | |
| h_{ie} | $V_{CE}=5.0\text{V}, I_C=1.0\text{mA}, f=1.0\text{kHz}$ | 6.0 | 20 | k Ω |
| h_{oe} | $V_{CE}=5.0\text{V}, I_C=1.0\text{mA}, f=1.0\text{kHz}$ | 5.0 | 50 | μS |
| h_{re} | $V_{CE}=5.0\text{V}, I_C=1.0\text{mA}, f=1.0\text{kHz}$ | | 10 | $\times 10^{-4}$ |
| NF | $V_{CE}=5.0\text{V}, I_C=250\mu\text{A}, R_S=1.0\text{k}\Omega$ $f=1.0\text{kHz}, BW=150\text{Hz}$ | | 2.0 | dB |
| NF | $V_{CE}=5.0\text{V}, I_C=20\mu\text{A}, R_S=10\text{k}\Omega$ $f=1.0\text{kHz}, BW=150\text{Hz}$ | | 2.0 | dB |

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TO-92 CASE - MECHANICAL OUTLINE



R1

| SYMBOL | INCHES | | MILLIMETERS | |
|---------|--------|-------|-------------|------|
| | MIN | MAX | MIN | MAX |
| A (DIA) | 0.175 | 0.205 | 4.45 | 5.21 |
| B | 0.170 | 0.210 | 4.32 | 5.33 |
| C | 0.500 | - | 12.70 | - |
| D | 0.016 | 0.022 | 0.41 | 0.56 |
| E | 0.100 | | 2.54 | |
| F | 0.050 | | 1.27 | |
| G | 0.125 | 0.165 | 3.18 | 4.19 |
| H | 0.080 | 0.105 | 2.03 | 2.67 |
| I | 0.015 | | 0.38 | |

TO-92 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING:

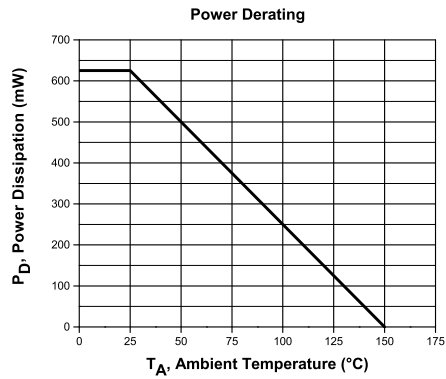
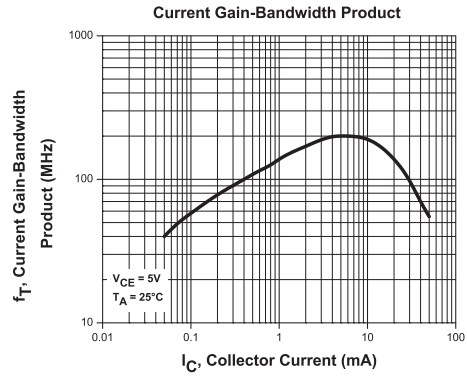
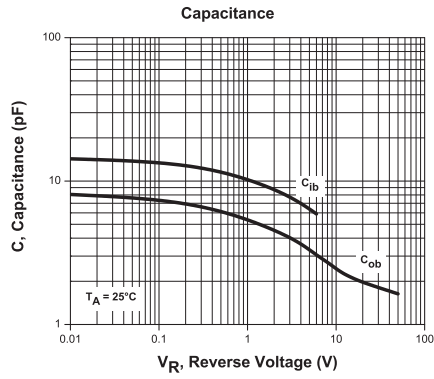
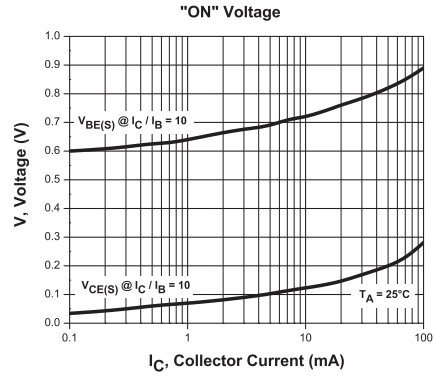
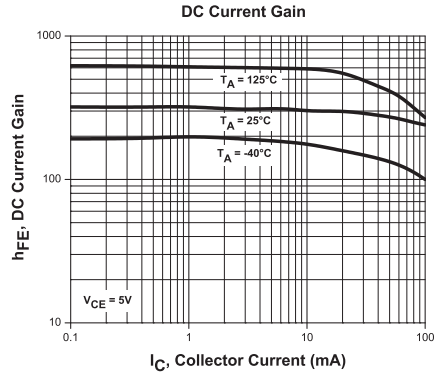
FULL PART NUMBER

R0 (26-July 2013)

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TYPICAL ELECTRICAL CHARACTERISTICS



R0 (26-July 2013)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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